

66359

4 kV OPTOCOUPLER



09/18/2012

Features:

- 5 kV Isolation Voltage
- 850 nm Emitters
- 4 kV Output Reverse Breakdown Voltage
- Radiation tolerant by design

Applications

- High Voltage Power Supplies
- High Voltage Instruments
- Voltage Level Shifting
- Space Instrumentation

DESCRIPTION

The **66359** is a single channel 4 kV Optocoupler using 850 nm Infrared Light Emitting Diodes optically coupled to a series of high voltage Silicon Photodiodes. The High Voltage Optocoupler is mounted into a non hermetic 4 Pin custom package designed to withstand high isolation voltage and is available as a commercial device or screened according to methods of MIL-PRF-38534 (where applicable).

ABSOLUTE MAXIMUM RATINGS ($t_A = 25^\circ\text{C}$ unless otherwise noted)

Operating Free-Air Temperature Range	-40°C to +100°C
Storage Temperature.....	-40°C to +100°C
Lead Soldering Temperature (1.6 mm from case for 5 seconds).....	240°C
Input to output Isolation Voltage (Note 1).....	5 kVDC

Input Diode:

Reverse Voltage (at 25°C case temperature)	3 VDC
Peak Forward Current (1µs pulse width, 300 pps).....	1 A
Forward Current-Continuous at 25°C case temperature	100 mA
Input Power Dissipation (Note 2).....	550 mW

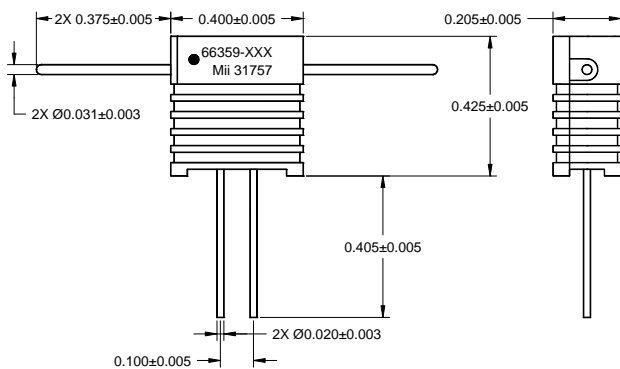
Output Photodetector:

Output Reverse Breakdown Voltage.....	4 kVDC
Continuous Detector Current (V_{OUT} or P_{OUT} dependent) @ 2.5 kV	600 µA
Power Dissipation at 25°C case temperature (Note 3)	1.5 W

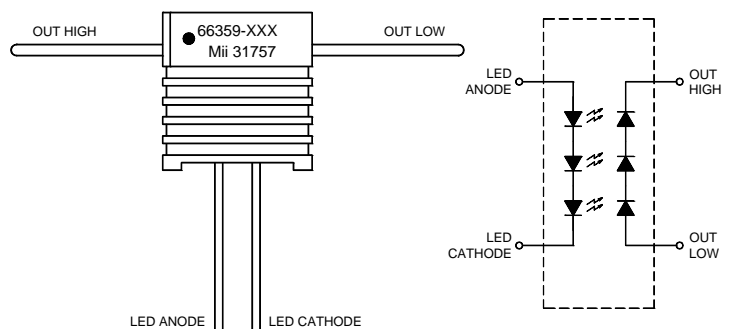
NOTES:

1. Measured with input leads shorted together and output leads shorted together.
2. Derate linearly at the rate of 15 mW/°C above 65°C case.
3. Derate linearly at the rate of 40 mW/°C above 65°C case.

Package Dimensions



Schematic Diagram



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4 kV OPTOCOUPLER**ELECTRICAL CHARACTERISTICS**T_A = 25°C unless otherwise specified.

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS	NOTE
Input Characteristic							
Input Forward Voltage	V _{F(IN)}	3.8		4.5	V	I _F = 20 mA	
		4.3		5.6		I _F = 100 mA	
Input Reverse Current	I _R			1	μA	V _R = 3 V	
Output Characteristic							
Output Forward Voltage	V _{F(OUT)}	2.0		3.0	V	I _F = 20 mA	
		3.0		4.0		I _F = 100 mA	
Reverse Breakdown Voltage	V _{BR}	4			kV	I _d = 1 μA	
Coupled Characteristic							
Input-Output Isolation Current	I _{IO}			10	μA	V _{IO} = 5 kV	
Dark Current	I _D			10	nA	I _F = 0 mA, V _{OUT} = 2.5 kV	
				25		I _F = 0 mA, V _{OUT} = 4 kV	
Current Transfer Ratio	CTR	2.0			%	I _F = 20 mA, V _{OUT} = 0 V	
		2.2				I _F = 100 mA, V _{OUT} = 0 V	
		3.0				I _F = 20 mA, V _{OUT} = 750 V	
		3.5				I _F = 20 mA, V _{OUT} = 2.5 kV	

RECOMMENDED OPERATING CONDITIONS:

PARAMETER	SYMBOL	MIN	MAX	UNITS
Forward Current	I _F		20	mA

SELECTION GUIDE

PART NUMBER	PART DESCRIPTION
66359-001	Commercial
66359-101	Screened